

Notice of References Cited				Application No. 09/319,699		Applicant(s) Lippert et al.	
				Examiner Douglas Wille		Group Art Unit 2814	

U.S. PATENT DOCUMENTS						
*	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	
x	A	5,557,118	9/1996	Hasimoto	257	197
	B					
	C					
	D					
	E					
	F					
	G					
	H					
	I					
	J					
	K					
	L					
	M					

FOREIGN PATENT DOCUMENTS						
*	DOCUMENT NO.	DATE	COUNTRY	NAME	CLASS	SUBCLASS
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS		
*	DOCUMENT (Including Author, Title, Source, and Pertinent Pages)	DATE
x	U Lanzerotti et al. Si/SiGeC/Si Heterojunction Bipolar Transistors IEEE Elec. Dev. V-17 pp 334-337	7/1996
x	V Lanzerotti et al. Suppression of Boron Outdiffusion in SiGe HBTs by Carbon Incorporation IEDM-96 pp 249-252	8-10 DEC 12/1996
	W	
	X	

* A copy of this reference is not being furnished with this Office action.
(See Manual of Patent Examining Procedure, Section 707.05(a).)